# NSN 5962-01-351-4967

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View Online at https://aerobasegroup.com/nsn/5962-01-351-4967

Overall Length:
1.060 inches
Overall Height:
0.400 inches
Body Length:
1.060 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.130 inches and 0.185 inches
Maximum Power Dissipation Rating:
300.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Satellite communications terminal an/usc-3 (v) 1
Features Provided:
High impedance and monolithic and w/clock and w/enable and w/disable and electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Case Outline Source And Designator:
D-8 mil-m-38510
Current Rating Per Characteristic:
50.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Pal pre-synchronizer
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 12.0 volts power source
Time Rating Per Chacteristic:
75.00 nanoseconds propagation delay time, high to low level output and 75.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:

Pal

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#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

## Unit Of Measure:

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### Demilitarization:

Yes - demil/mli

Fiig:

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